#### Docket No.

# Declaration and Power of Attorney for U.S. Patent Application

## 特許出願宣言書及び委任状

# Japanese Language Declaration

#### 日本語宣言書

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下での氏名の発明者として、私は以下の通り宣言します。	As a below named inventor, I hereby declare that:
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開設和の住所、私書箱、国籍は下記の私の氏名の後に記載され 開発通りです。 は後	My residence, post office address and citizenship are as stated next to my name.
無行 で	I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled
	HIGH FREQUENCY SEMICONDUCTOR DEVICE
上記発明の明細書(下記の欄でx印がついていない場合は、本書に添付)は、	the specification of which is attached hereto unless the following box is checked:
□ 月日に提出され、米国出願番号または特許協定条約 □	was filed onas United States Application Number or PCT International Application Number and was amended on (if applicable).
私は、特許請求範囲を含む上記訂正後の明知書を検討し、 内容を理解していることをここに表明します。	I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.
私は、連邦規則法典第37編第1条56項に定義されると おり、特許資格の有無について重要な情報を開示する義務が あることを認めます。	l acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56.
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#### Japanese Language Declaration (日本語宣言書)

私は、米国法典第35編119条(a)-(d)項又は365条(b)項に基さ下記の、米国以外の国の少なくとも一ヵ国を指定している特許協力条約365(a)項に基ずく国際出願、又は外国での特許出願もしくは発明者証の出願についての外国優先権をここに主張するとともに、優先権を主張している、本出顧の前に出願された特許または発明者証の外国出願を以下に、枠内をマークすることで、示しています。

Prior Foreign Application(s)

外国での先行出顔

...

2001-99961	Japan
(Number)	(Country)
(番号)	(国名)
(Number)	(Country)
(番号)	(国名)

私に、第35編米国法典119条(e)項に基いて下記の米 国特許出願規定に記載された権利をここに主張いたします。

(Application No.) (Filing Date) (出類母号) (出類日)

私は、下記の米国法典第35編120条に基いて下記の米国特許出願に記載された権利、又は米国を指定している特許協力条約365条(c)に基ずく権利をここに主張します。また、本出願の各請求範囲の内容が米国法典第35編112条第1項又は特許協力条約で規定された方法で先行する米国特許出願に開示されていない限り、その先行米国出願書提出日以降で本出願書の日本国内または特許協力条約国際提出日までの期間中に入手された、連邦規則法典第37編1条56項で定義された特許資格の有無に関する重要な情報について開示義務があることを認識しています。

(Application No.) (Filing Date) (出願冊号) (出願日)

(Application No.) (Filing Date) (出願日)

私は、私自身の知識に基ずいて本宣言書中で私が行なう表明が真実であり、かつ私の入手した情報と私の信じるところに基ずく芸明が全て真実であると信じていること、さらに故意になされた虚偽の表明及びそれと同等の行為は米国法典第18編第1001条に基ずき、罰金または拘禁、もしくはその両方により処罰されること。そしてそのような故意による虚偽の声明を行なえば、出願した、又は既に許可された特許の有効性が失われることを認識し、よってここに上記のごとく宣誓を致します。

I hereby claim foreign priority under Title 35, United States Code, Section 119 (a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate, or 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed.

Priority Not Claimed 優先権主張なし

30/March/2001 (Day/Month/Year Filed) (出版年月日) (Day/Month/Year Filed) (出版年月日)

I hereby claim the benefit under Title 35. United States Code, Section 119(e) of any United States provisional application(s) listed below.

(Application No.) (Filing Date) (出願音)

I hereby claim the benefit under Title 35, United States Code, Section 120 of any United States application(s), or 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of Title 35, United States Code Section 112, I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56 which became available between the filing date of the prior application and the national or PCT International filing date of application.

(Status: Patented, Pending, Abandoned) (現況: 特許許可済、係属中、放棄済)

(Status: Patented, Pending, Abandoned) (現況: 特許許可济、係属中、故藥济)

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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Docket No (cont'd.) ARMSTRONG, WESTERMAN, HATTORI, McLELA  Japanese Language Declaration (日本語宣言書)	AND & NAUC
委任状: 私は下記の発明者として、本出額に関する一切の 手続きを米特許商標局に対して遂行する弁理上または代理人 として、下記の者を指名いたします。(弁護上、または代理 人の氏名及び登録番号を明記のこと)  POWER OF ATTORNEY: As a named inventor, I have a polication and transact all business in the Patent an Office connected therewith (list name and registration See list of attorneys and/or agents on page 5.	osecute this d Trademark
查類送付先 Send Correspondence to:  ARMSTRONG, WESTERMAN, HATTORI,  McLELAND & NAUGHTON  1725 K Street, N.W., Suite 1000  Washington, D.C. 20006	
直接電話連絡先: (名前及び電話番号) Direct Telephone Calls to: (name and telephone number Telephone: (202) 659-2930 Fax: (202) 887-0357	
唯一または第一発明者名 Full name of sole or first inventor Yoshio AOKT	
全田子の署名 日付 Inventor's signature ナーナー Date	20, '02
程序 Feb. Residence Yamanashi, Japan Giltzenship Japan	
和查知 Post Office Address c/o FUJITSU QUANTUM DEVICES LIMI Oaza-Kamisukiawara, Showa-cho, 1	ITED,1000,
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第二共同発明者 目付 Second inventor's signature Date 早里子 彩 Feb. 2	20, '02
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私香箱 c/o FUJITSU QUANTUM DEVICES LIMITED, 1000, Oaza-Kamisukiawara, Showa-cho, Nakakoma-gun, Yamanashi 409-3883 Japan

(第三以降の共同発明者についても同様に記載し、署名をす ること)

(Supply similar information and signature for third and subsequent joint inventors.)

第三共同発明者		Full name of third joint inventor, if any	-			
		Osamu BABA				
第三発明者の署名	月付	Third inventor's signature	Date Feb.	20,	<b>'</b> 02	
<b>尘</b> 所		Residence Yamanashi, Ja	pan			
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<b>,</b>		gun, Yamanashi,409-3883	Japan			
第四共同発明者		Full name of fourth joint inventor, if any				
		Muneharu GOTOH				
第四発明者の署名	日付	Fourth inventor's signature	Date			
	••••	後樣才春	Feb.	20,	102	
住所		Residence		,	~~	
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第五共同発明者		Full name of fifth joint inventor, if any				
	·					
第五発明者の署名	H付·	Fifth inventor's signature	Date			
<b>全所</b>		Residence				
<b>料</b>		Citizenship				
私营箱		Post Office Address	<del></del>			
			<del></del>	<del></del>		
第六共同発明者		Full name of sixth joint inventor, if any	···-		v	
			<del></del>			
第六発明者の署名	日付	Sixth Inventor's signature	Date			
主所		Residence			<del></del>	
I #	<del></del>	: Citizenship				
私春新		Post Office Address				

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